CHINA
SEMICONDUCTOR
CORPORATION

Spec. No.	PS-ND-08090111
Rev.	A

PRODUCT SPECIFICATION

Model No：CST-532B7/533B7

Descriptions:

- 0.56 Inch Triad Digit Display
- CST-532: Common Anode
- CST-533: Common Cathode
- Emitting Color：Super Bright Blue

CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

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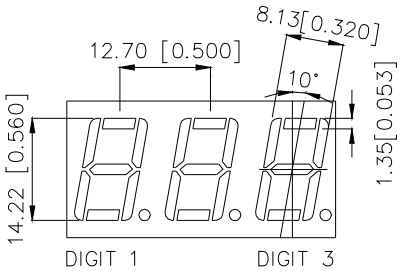
■ Features -

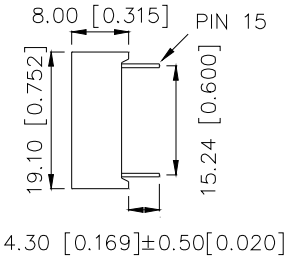
1. 0.56 inch (14.2mm) digit height.
2. Case mold type.
3. RoHS compliant.
4. Low power consumption.
5. ESD > 1KV(HBM)
6. Easy mounting on P.C. board or socket.

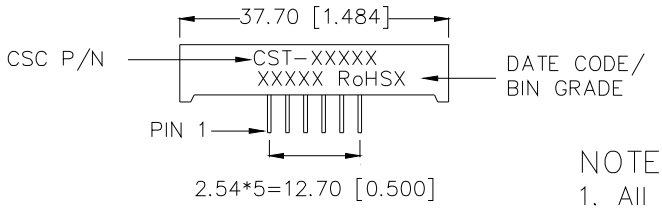
■ Device Selection Guide -

Part No.	Chip		Description
	Material	Emitted Color	
CST-532B7	InGaN	Super Bright Blue	Common Anode
CST-533B7	InGaN	Super Bright Blue	Common Cathode

■ Package Dimensions -







NOTE:
1. All pins are ø0.50[0.020].
2. Dimension in millimeters [inch], tolerance is ±0.25 [0.010] unless otherwise noted.

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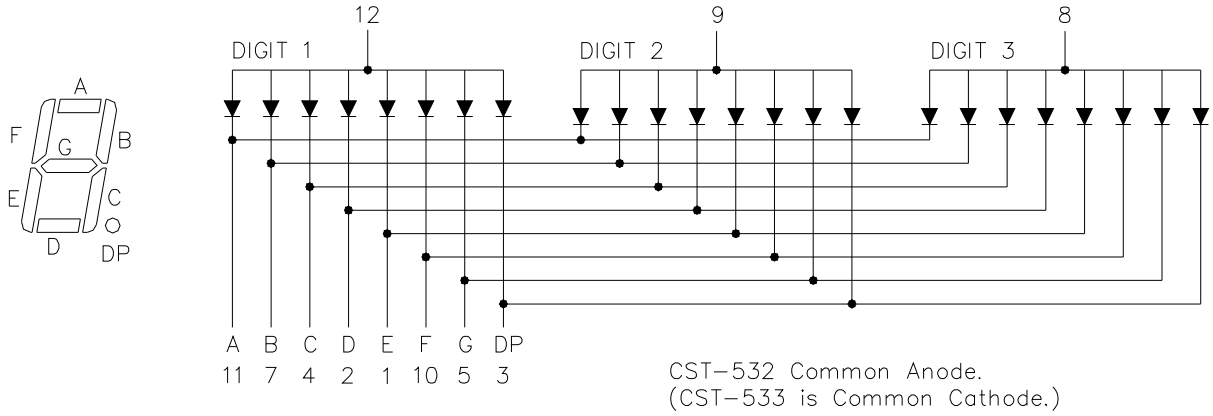
■ Internal Circuit Diagrams -



■ Absolute Maximum Rating -

(Ta=25℃)

Parameter	Symbol	Rating	Unit
Power Dissipation Per Dice	P_{AD}	120	mW
Continuous Forward Current Per Dice	I_{AF}	30	mA
Peak Current Per Dice(duty cycle 1/10, 1kHz)	I_{PF}	100	mA
Derating Linear From 25℃ Per Dice	-	0.4	mA/℃
Reverse Voltage Per Dice	V_R	5	V
Operating Temp.	Topr	-35 ~ +85	℃
Storage Temp.	Tstg	-35 ~ +85	℃
Solder temperature 1/16 inch below seating plane for 3 seconds at 260℃			

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■ Electro-optical Characteristics -

(Ta=25℃)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage Per Segment	V_F	-	3.5	4	V	I_F=20mA
Luminous Intensity Per Segment	Iv	-	20	-	mcd	I_F=10mA
Peak Emission Wavelength	λp	-	468	-	nm	I_F=20mA
Dominant Wavelength	λd	-	470	-	nm	I_F=20mA
Spectrum Radiation Bandwidth	$\Delta \lambda$	-	30	-	nm	I_F=20mA
Reverse Current	IR	-	-	100	μA	V_R=5V
Luminous Intensity Matching Ratio	IV-m	-	-	2:1	-	I_F=10mA

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■ Typical Electrical / Optical Charateristics Curves -

(Ta = 25℃ Unless Otherwise Noted)

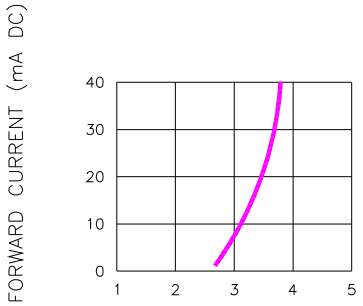

Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE

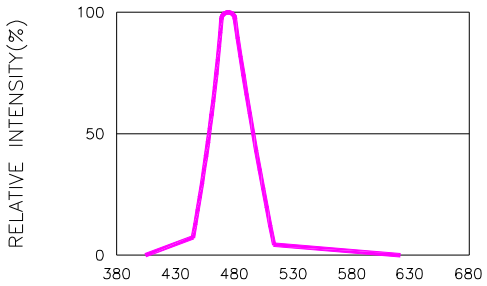

Fig.2 RELATIVE INTENSITY VS. WAVELENGTH

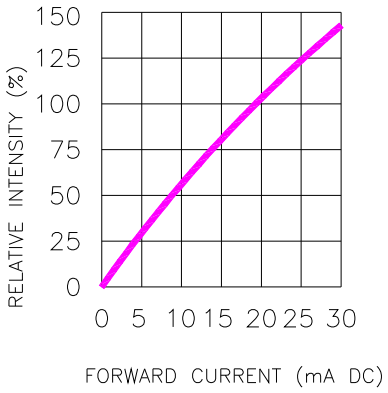

Fig.3 RELATIVE INTENSITY
VS. FORWARD CURRENT

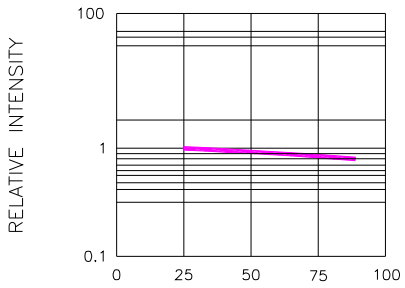

Fig.4 RELATIVE INTENSITY VS.LEAD TEMPERATURE
(PULSED 20 mA; 300us
PULSE,10ms PERIOD)

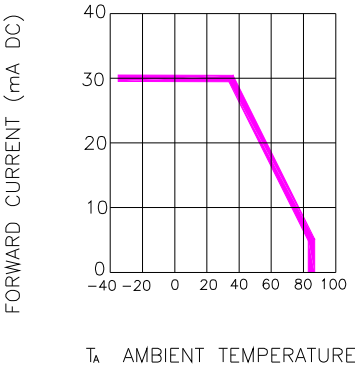

Fig.5 FORWARD CURRENT
VS. AMBIENT TEMPERATURE

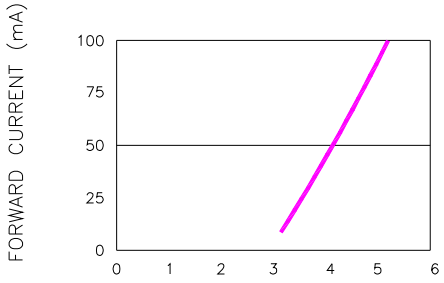

Fig.6 PEAK FORWARD VOLTAGE
VS.FORWARD(100us TEST PULSE,
1% DUTY CYCLE)

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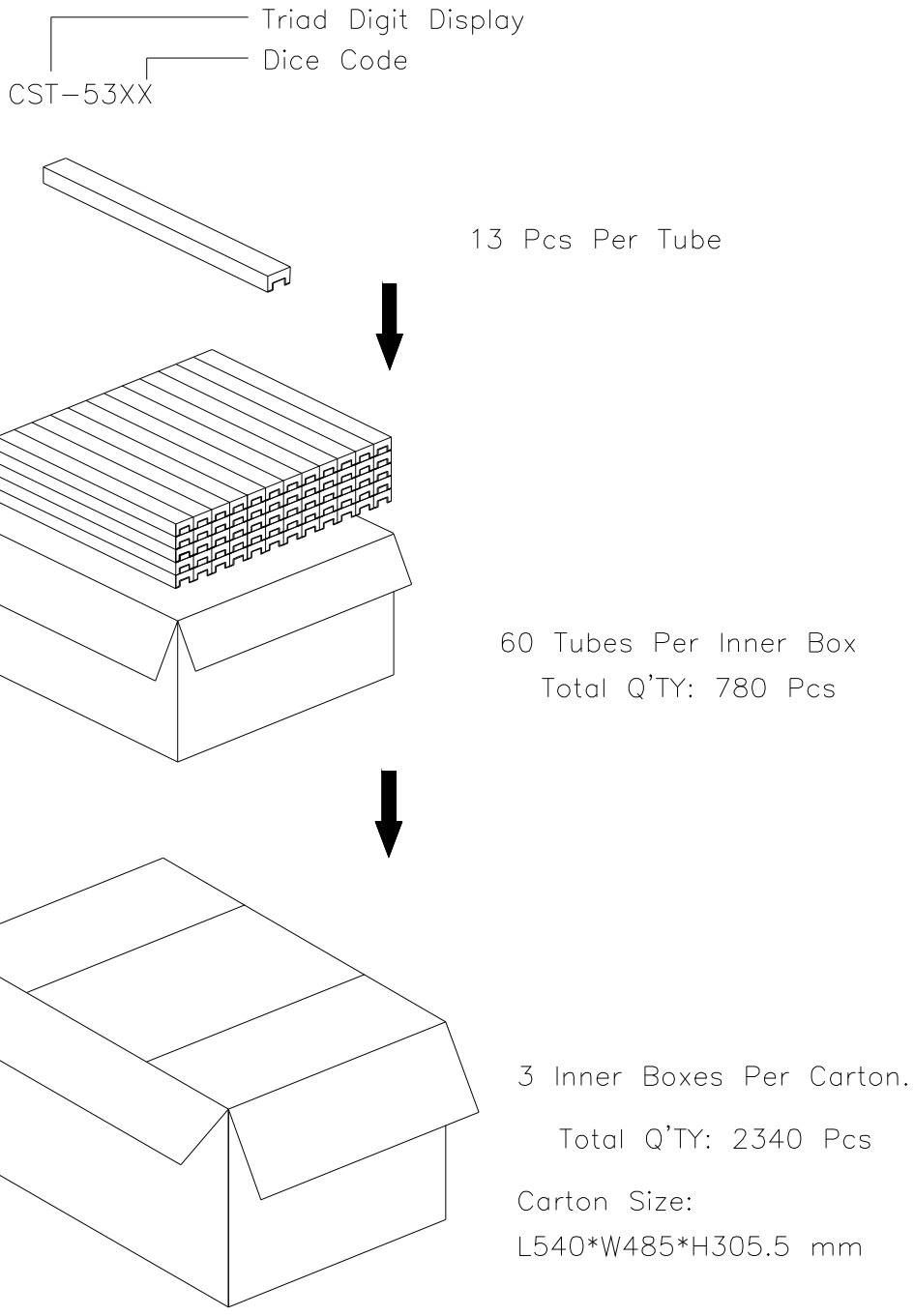
■ Package Dimensions



Note: The specifications are subject to change without notice. Please contact us for updated information.